

50V NPN LOW SATURATION POWER TRANSISTOR IN SOT89

Features

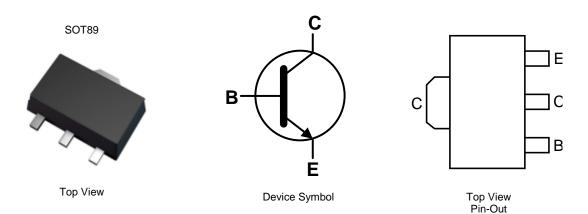
- BV_{CEO} > 50V
- I_C = 3A High Continuous Collector Current
- I_{CM} up to 6A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 220mV @ 1A
- R_{CE(sat)} = 87mΩ @ 2.75A for a Low Equivalent On-Resistance
- hFE Characterized up to 6A for High Current Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.052 grams (Approximate)

Applications

- Load Management Functions
- Motor Control
- DC-DC / DC-AC Converters



Ordering Information (Notes 4 and 5)

Part number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX619TA	AEC-Q101	619	7	12	1,000
FCX619-13R	AEC-Q101	619	13	12	4,000
FCX619QTA	Automotive	619	7	12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

 Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	lc	3	A
Peak Pulse Current	I _{CM}	6	A
Continuous Base Current	IB	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		0.7		
Power Discinction	(Note 7)	PD	1.0	W	
Power Dissipation	(Note 8)		1.5		
	(Note 9)		2.0		
	(Note 6)	R _θ JA	178		
Thermal Desistance Junction to Ambient Air	(Note 7)		125		
Thermal Resistance, Junction to Ambient Air	(Note 8)		83	°C/W	
	(Note 9)		62.5		
Thermal Resistance, Junction to Lead	(Note 10)	R _{θJL}	6]	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 11)

Notes:

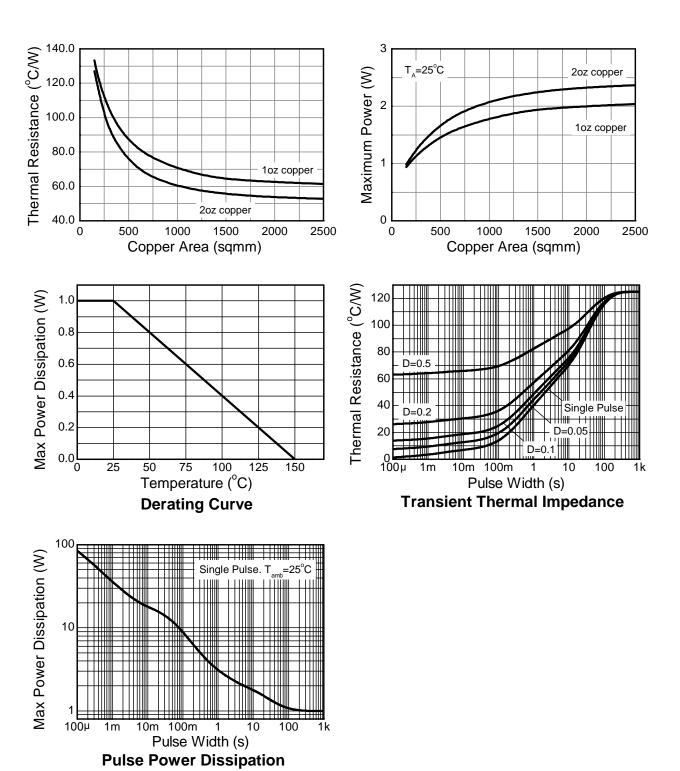
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted with the exposed collector pad on minimum recommended pad layout (MRP) 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as Note 6, except the device is mounted with the exposed collector pad on 15mm x 15mm 1oz copper.
8. Same as Note 6, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.
9. Same as Note 6, except the device is mounted with the exposed collector pad on 40mm x 40mm 1oz copper.

10. Thermal resistance from junction to solder-point (on the exposed collector pad).

11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.







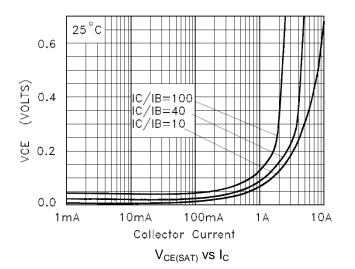
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

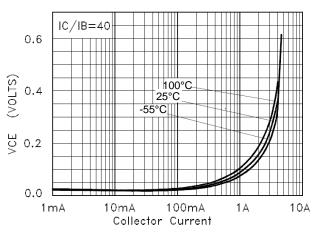
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	190	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 12)	BVCEO	50	65	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	—	V	I _E = 100μA
Collector Cutoff Current	ICBO	_	—	100	nA	$V_{CB} = 40V$
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	V _{EB} = 5.6V
Emitter Cutoff Current	ICES	-	_	100	nA	$V_{CES} = 40V$
DC Current Transfer Static Ratio (Note 12)	hfe	200 300 200 100 —	400 450 400 200 30	_	_	
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(sat)}	_	13 150 190 240	25 220 260 320	mV	$I_{C} = 100 \text{mA}, I_{B} = 10 \text{mA}$ $I_{C} = 1 \text{A}, I_{B} = 10 \text{mA}$ $I_{C} = 2 \text{A}, I_{B} = 50 \text{mA}$ $I_{C} = 2.75 \text{A}, I_{B} = 100 \text{mA}$
Base-Emitter Saturation Voltage (Note 12)	V _{BE(sat)}	_	0.97	1.1	V	I _C = 2.75A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 12)	V _{BE(on)}	_	0.89	1	V	$I_{C} = 2.75A, V_{CE} = 2V$
Transitional Frequency	f _T	100	165	_	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
Output Capacitance	C _{obo}		12	20	pF	$V_{CB} = 10V, f = 1MHz,$
Turn-On Time	t _(on)		170		ns	V _{CC} = 10V, I _C =1A
Turn-Off Time	t _(off)	—	750	_	ns	$I_{B1} = 10mA,$ $I_{B2} = -10mA$

Note: 12. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

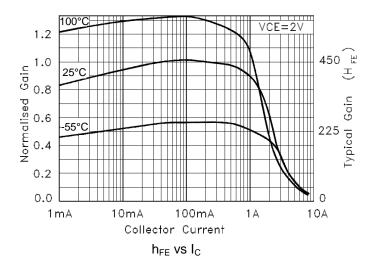


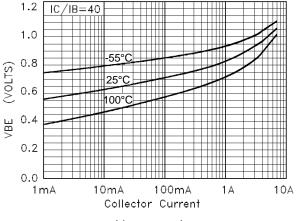
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



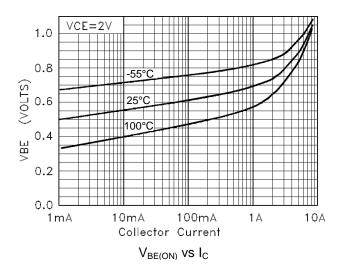


 $V_{CE(SAT)}$ vs I_C





 $V_{\text{BE(SAT)}} \text{ vs } I_{C}$



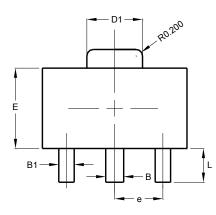


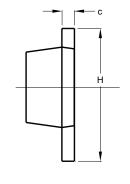
FCX619

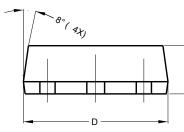
Package Outline Dimensions

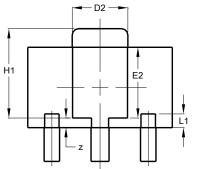
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







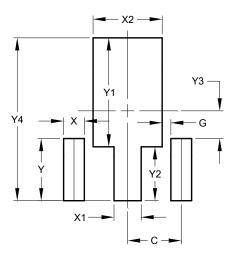


SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
с	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
ш	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	-	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)	
С	1.500	
G	0.244	
Х	0.580	
X1	0.760	
X2	1.933	
Y	1.730	
Y1	3.030	
Y2	1.500	
Y3	0.770	
Y4	4.530	



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